

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	124	TiN near7 ((bottom or lower or first) adj (electrode or conductive or plate)) same CVD	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
2	BRS	L2	86	@ad<=20010630 and 1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
3	BRS	L3	26	polysilicon same 1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
4	BRS	L7	541	(polysilicon near7 plug) same silicide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
5	BRS	L8	350	capacitor and 7	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
6	BRS	L9	266	@ad<=20010630 and 8	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
7	BRS	L13	31	("H.sub.2SO.sub.4" near7 "H.sub.2O.sub.2") same silicide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
8	BRS	L14	12	@ad<=20010630 and 13	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB